NSN 5961-01-313-1429

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Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-313-1429 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Criticality Code Justification:** Cbbl **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 drain to source voltage and 30.0 drain to gate voltage and 30.0 gate to source voltage **Current Rating Per Characteristic:** 30.00 milliamperes drain current **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 26916-019-005539 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**